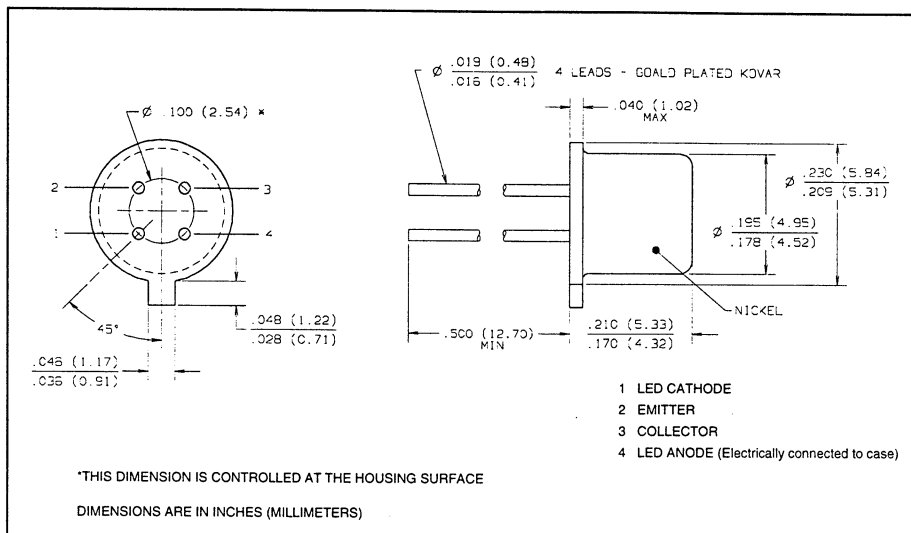
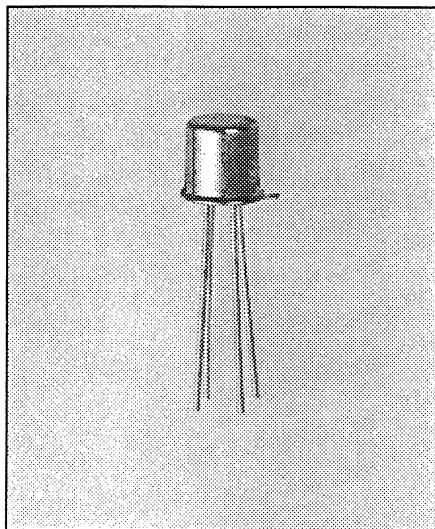


Optically Coupled Isolator

Type 3C92C, 3C92CHR, 3C92CTX, 3C92CTXV



Features

- TO-72 hermetic package
- 1 kVDC electrical isolation
- High current transfer ratio

Description

The 3C92C is an optically coupled isolator consisting of an infrared emitting diode and an NPN silicon phototransistor mounted in a hermetically sealed TO-72 package.

Typical screening and lot acceptance tests are provided on page 13-4.

The 3C92CHR device has been 100% screened as a TXV device although Group B and C testing is not performed.

Absolute Maximum Ratings ($T_A = 25^\circ \text{C}$ unless otherwise noted)

Input to Output Isolation Voltage	$\pm 1 \text{ kVDC}^{(1)}$
Operating Temperature Range	-55°C to $+125^\circ \text{C}$
Storage Temperature Range	-65°C to $+150^\circ \text{C}$
Lead Soldering Temperature [1/16 inch (1.6 mm) from case, 5 sec. with soldering iron]	$240^\circ \text{C}^{(2)}$
Power Dissipation (Output Transistor)	$200 \text{ mW}^{(3)}$
Power Dissipation (Input Diode)	$60 \text{ mW}^{(4)}$

Notes:

- (1) Measured with input leads shorted together and output leads shorted together.
- (2) RMA flux is recommended. Duration can be extended to 10 sec. max. when flow soldering.
- (3) Derate linearly $2.0 \text{ mW}/^\circ \text{C}$ above 25°C .
- (4) Derate linearly $0.60 \text{ mW}/^\circ \text{C}$ above 65°C .

Types 3C92C, 3C92CHR, 3C92CTX, 3C92CTXV

Electrical Characteristics ($T_A = 25^\circ \text{C}$ unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITION
Input Diode						
V_F	Forward Voltage			1.2 1.5	V V	$I_F = 2 \text{ mA}$ $I_F = 50 \text{ mA}$
V_R	Reverse Voltage	7			V	$I_R = 0.1 \text{ mA}$
I_R	Reverse Current			1	μA	$V_R = 3 \text{ V}$
C_{IN}	Diode Capacitance		25		pF	$V = 0, f = 1 \text{ MHz}$
Phototransistor						
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	50			V	$I_C = 10 \text{ mA}$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	7			V	$I_C = 10 \mu\text{A}$
I_{CEO}	Collector-Emitter Leakage Current			10 50	nA nA	$V_{CE} = 5 \text{ V}$ $V_{CE} = 50 \text{ V}$
Coupled						
$I_{C(ON)}$	On-State Collector Current	4.0 3.0		— 20	mA mA	$I_F = 10 \text{ mA}, V_{CE} = 5 \text{ V}$ $I_F = 10 \text{ mA}, V_{CE} = 0.4 \text{ V}$
$V_{CE(SAT)}$	Collector-Emitter Saturation Voltage			0.4	V	$I_F = 50 \text{ mA}, I_C = 10 \text{ mA}$
t_{on}	Turn on Time			9	μs	$V_{CC} = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$
t_{off}	Turn off Time			6	μs	
C_{IO}	Input-to-Output Capacitance		2	2.5	pF	$f = 1 \text{ MHz}$
R_{IO}	Isolation Resistance	10^9			Ω	$V_{IO} = +1 \text{ kV}$

HI-REL OPTO
COMPONENTS